1PSxSB17

4 V, 30 mA low C_d Schottky barrier diode

Rev. 06 — 4 April 2005

Product data sheet

1. Product profile

1.1 General description

Planar low capacitance Schottky barrier diode encapsulated in a very small SMD plastic package.

Table 1: Product overview

Type number	Package		Configuration
	Philips	JEITA	
1PS66SB17	SOT666	-	triple isolated diode
1PS76SB17	SOD323	SC-76	single diode
1PS79SB17	SOD523	SC-79	single diode

1.2 Features

- Very low diode capacitance
- Very low forward voltage
- Very small SMD plastic packages

1.3 Applications

- Digital applications:
 - Ultra high-speed switching
 - Clamping circuits.
- RF applications:
 - Diode ring mixer
 - RF detector
 - RF voltage doubler

1.4 Quick reference data

Table 2: Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
l _F	continuous forward current		-	-	30	mA
V _R	continuous reverse voltage		-	-	4	V
C _d	diode capacitance		-	0.8	1	pF





2. Pinning information

Table 3: Pinning

Pin	Description	Simplified outline	Symbol
SOD323	(SC-76); SOD523 (SC-79)		
1	cathode	[1]	n 4
2	anode	1	1 🙌 2
			sym001
		001aab540	
SOT666			

001000		
1	anode (diode 1)	
2	anode (diode 2)	6 5 4
3	anode (diode 3)	
4	cathode (diode 3)	
5	cathode (diode 2)	
6	cathode (diode 1)	1 2 3

^[1] The marking bar indicates the cathode.

3. Ordering information

Table 4: Ordering information

Type number	Package	Package				
	Name	Description	Version			
1PS66SB17	-	plastic surface mounted package; 6 leads	SOT666			
1PS76SB17	SC-76	plastic surface mounted package; 2 leads	SOD323			
1PS79SB17	SC-79	plastic surface mounted package; 2 leads	SOD523			

4. Marking

Table 5: Marking codes

Type number	Marking code
1PS66SB17	N2
1PS76SB17	S7
1PS79SB17	T2

5. Limiting values

Table 6: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_R	continuous reverse voltage		-	4	V
l _E	continuous forward current		-	30	mA

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Table 6: Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

6. Thermal characteristics

Table 7: Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient;	in free air	<u>[1]</u>			
	SOD323		[2] _	-	450	K/W
	SOD523		[3]	-	450	K/W
	SOT666		[4]	-	700	K/W

^[1] For Schottky barrier diodes, thermal run-away has to be considered as in some applications the reverse power losses P_R are a significant part of the total power losses. Nomograms for determining the reverse power losses P_R and $I_{F(AV)}$ rating will be available on request.

7. Characteristics

Table 8: Characteristics

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{F}	forward voltage	see Figure 1;	<u>[1]</u>			
		I _F = 0.1 mA	-	300	350	mV
		I _F = 1 mA	-	360	450	mV
		I _F = 10 mA	-	470	600	mV
I _R	reverse current	V _R = 3 V; see Figure 2	-	-	250	nA
C _d	diode	see Figure 3;				
	capacitance	V _R = 0 V; f = 1 MHz	-	0.8	1	pF
		V _R = 0.5 V; f = 1 MHz	-	0.65	-	pF

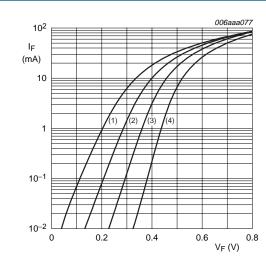
^[1] Pulse test: $t_p \le 300 \ \mu s; \ \delta \le 0.02.$

^[2] Refer to SOD323 (SC-76) standard mounting conditions.

^[3] Refer to SOD523 (SC-79) standard mounting conditions.

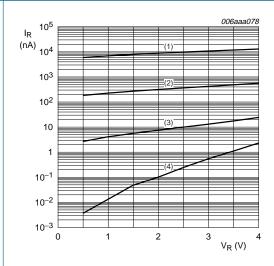
^[4] Refer to SOT666 standard mounting conditions.





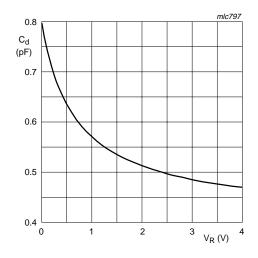
- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 85 \, ^{\circ}C$
- (3) $T_{amb} = 25 \, ^{\circ}C$
- (4) $T_{amb} = -40 \, ^{\circ}C$

Fig 1. Forward current as a function of forward voltage; typical values.



- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 85 \,^{\circ}C$
- (3) $T_{amb} = 25 \,^{\circ}C$
- (4) $T_{amb} = -40 \, ^{\circ}C$

Fig 2. Reverse current as a function of reverse voltage; typical values.



 T_{amb} = 25 °C; f = 1 MHz

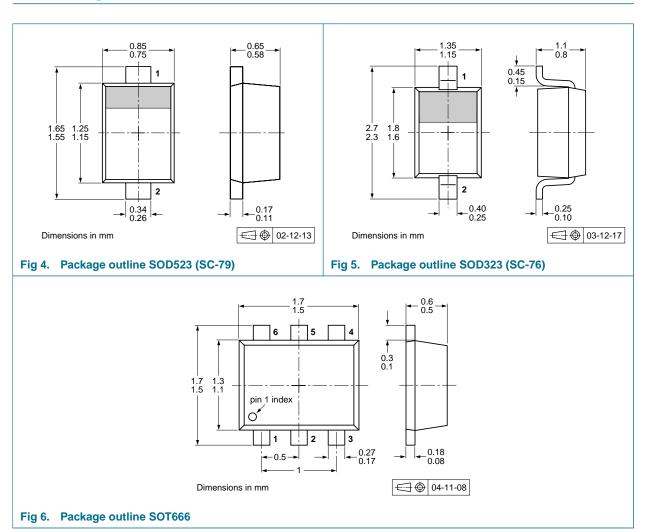
Fig 3. Diode capacitance as a function of reverse voltage; typical values.

Product data sheet





8. Package outline



9. Packing information

Table 9: Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code. [1]

Type number	Package	Description	Packing quantity		
			3000	4000	10000
1PS66SB17	SOT666	4 mm pitch, 8 mm tape and reel	-	-115	-
1PS76SB17	SOD323	4 mm pitch, 8 mm tape and reel	-115		-135
1PS79SB17	SOD523	4 mm pitch, 8 mm tape and reel	-115		-135

 $[\]begin{tabular}{ll} [1] & For further information and the availability of packing methods, see $$\underline{$\sf Section 14}$. \\ \end{tabular}$

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10. Revision history

Table 10: Revision history

Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes
1PSXSB17_6	20050404	Product data sheet	-	9397 750 14587	1PS76SB17_1 PS79SB17_5
Modifications:	 Type numl 	ber 1PS66SB17 added			
1PS76SB17_1PS79SB17_5	20041028	Product data sheet	-	9397 750 13733	1PS76SB17_4
1PS76SB17_4	20040126	Product data sheet	-	9397 750 12618	1PS76SB17_3
1PS76SB17_3	20020809	Product data sheet	-	9397 750 10174	1PS76SB17_2
1PS76SB17_2	19990525	Preliminary data sheet	-	9397 750 05893	1PS76SB17_1
1PS76SB17_1	19961014	Preliminary data sheet	-	9397 750 01342	-



11. Data sheet status

Level	Data sheet status [1]	Product status [2] [3]	Definition
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